Old Company Name in Catalogs and Other Documents

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April 1st, 2010 Renesas Electronics Corporation

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ENESA

MOS FIELD EFFECT TRANSISTOR

NP80N055MDG, NP80N055NDG, NP80N055PDG

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The NP80N055MDG, NP80N055NDG, and NP80N055PDG are N-channel MOS Field Effect Transistors designed for high current switching applications.

ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
NP80N055MDG-S18-AY Note		Tube	TO-220 (MP-25K) typ. 1.9 g
NP80N055NDG-S18-AY		50 p/tube	TO-262 (MP-25SK) typ. 1.8 g
NP80N055PDG-E1B-AY	Pure Sn (Tin)	Таре	
NP80N055PDG-E2B-AY		1000 p/reel	TO-263 (MP-25ZP) typ. 1.5 g

Note Pb-free (This product does not contain Pb in the external electrode.)

FEATURES

- Logic level
- Super low on-state resistance
- NP80N055MDG, NP80N055NDG

 $R_{DS(on)1}$ = 6.9 m Ω MAX. (V_{GS} = 10 V, I_D = 40 A)

 $R_{DS(on)2} = 11.2 \text{ m}\Omega \text{ MAX.} (V_{GS} = 4.5 \text{ V}, I_D = 35 \text{ A})$

- NP80N055PDG

 $R_{DS(on)1}$ = 6.6 m Ω MAX. (V_{GS} = 10 V, I_D = 40 A)

 $R_{DS(on)2}$ = 10.9 m Ω MAX. (VGS = 4.5 V, ID = 35 A)

• High current rating

ID(DC) = ±80 A

Low input capacitance

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Ciss = 4600 pF TYP.
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• Designed for automotive application and AEC-Q101 qualified

(TO-220)





(TO-263)



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Document No. D19796EJ1V0DS00 (1st edition) Date Published May 2009 NS Printed in Japan

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Drain to Source Voltage (VGs = 0 V)	VDSS	55	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±80	А
Drain Current (pulse) ^{Note1}	D(pulse)	±200	А
Total Power Dissipation (Tc = 25° C)	P T1	115	W
Total Power Dissipation (T _A = 25°C)	Pt2	1.8	W
Channel Temperature	Tch	175	°C
Storage Temperature	Tstg	–55 to +175	°C
Repetitive Avalanche Current Note2	IAR	33	А
Repetitive Avalanche Energy Note2	Ear	111	mJ

Notes 1. $PW \leq$ 10 $\mu s, \, Duty \, Cycle \leq$ 1%

2. T_{ch} \leq 150°C, R_G = 25 Ω

THERMAL RESISTANCE

Channel to Case Thermal Resistance	Rth(ch-C)	1.30	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	83.3	°C/W

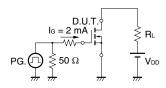
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 55 V, V _{GS} = 0 V			1	μA
Gate Leakage Current	Igss	V _{GS} = ±20 V, V _{DS} = 0 V			±100	nA
Gate to Source Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 <i>µ</i> A	1.4		2.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = 5 V, I _D = 35 A	25	64		S
Drain to Source On-state Resistance Note	RDS(on)1	V _{GS} = 10 V, I _D = 40 A NP80N055MDG, NP80N055NDG		5.4	6.9	mΩ
		V _{GS} = 10 V, I _D = 40 A NP80N055PDG		4.8	6.6	mΩ
	RDS(on)2	V _{GS} = 4.5 V, I _D = 35 A NP80N055MDG, NP80N055NDG		6.3	11.2	mΩ
		V _{GS} = 4.5 V, I _D = 35 A NP80N055PDG		5.9	10.9	mΩ
Input Capacitance	Ciss	V _{DS} = 25 V,		4600	6900	pF
Output Capacitance	Coss	V _{GS} = 0 V,		390	590	pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		240	430	pF
Turn-on Delay Time	td(on)	V _{DD} = 28 V, I _D = 40 A,		17	37	ns
Rise Time	tr	V _{GS} = 10 V,		13	33	ns
Turn-off Delay Time	td(off)	R _G = 0 Ω		77	154	ns
Fall Time	tr			7	18	ns
Total Gate Charge	QG	V _{DD} = 44 V,		90	135	nC
Gate to Source Charge	QGS	V _{GS} = 10 V,		13		nC
Gate to Drain Charge	Qgd	ID = 80 A		26		nC
Body Diode Forward Voltage Note	VF(S-D)	IF = 80 A, VGS = 0 V		0.95	1.5	V
Reverse Recovery Time	trr	IF = 80 A, VGS = 0 V,		38		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>µ</i> s		45		nC

Note Pulsed test

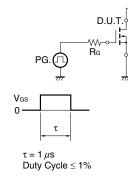
TEST CIRCUIT 1 AVALANCHE CAPABILITY

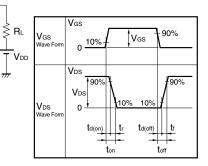
$V_{GS} = 20 \rightarrow 0 V$ $PG. \qquad PG. \qquad PG. \qquad PG. \qquad V_{DD}$ $V_{DD} \qquad V_{DD}$

TEST CIRCUIT 3 GATE CHARGE

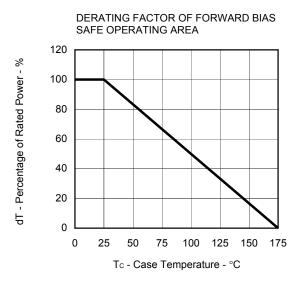


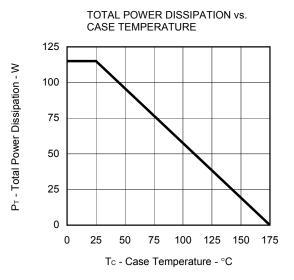
TEST CIRCUIT 2 SWITCHING TIME



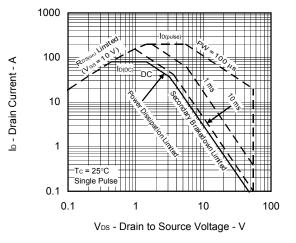


TYPICAL CHARACTERISTICS (TA = 25°C)

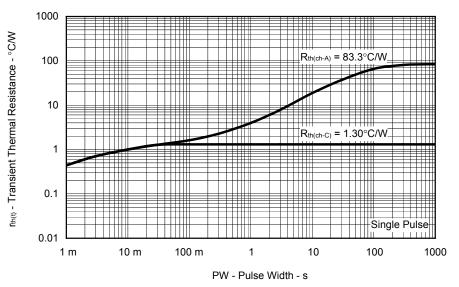




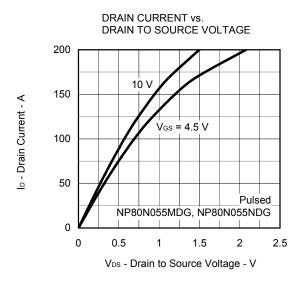




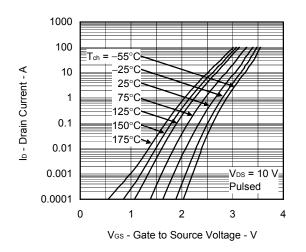
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

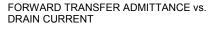


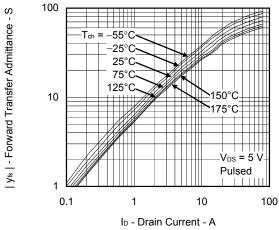
Data Sheet D19796EJ1V0DS

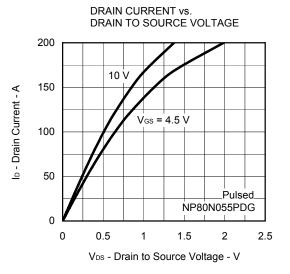




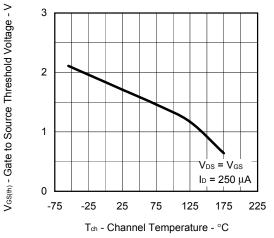








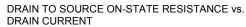
GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE

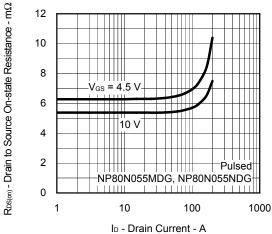


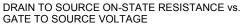
 $R_{DS(cn)}$ - Drain to Source On-state Resistance - m Ω

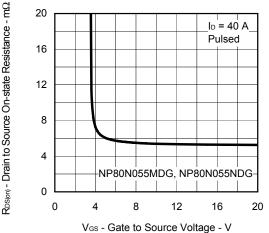
 $R_{DS(on)}$ - Drain to Source On-state Resistance - $m\Omega$

 $R_{DS(on)}$ - Drain to Source On-state Resistance - $m\Omega$

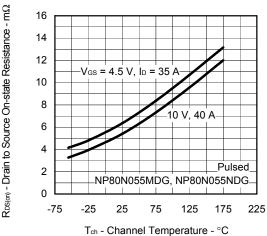




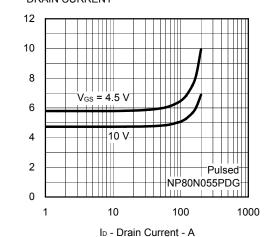




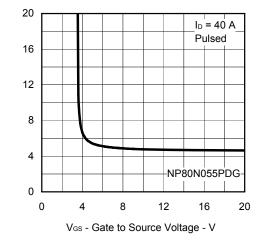
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



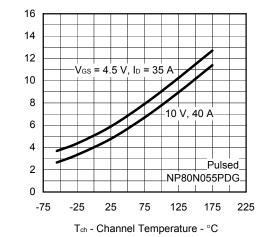
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

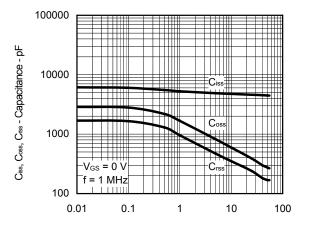


DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE

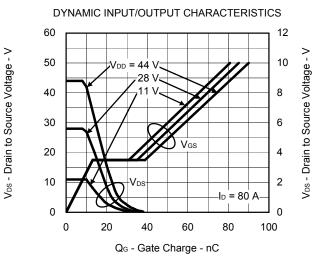


NEC

CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE

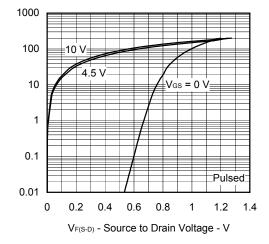


VDS - Drain to Source Voltage - V

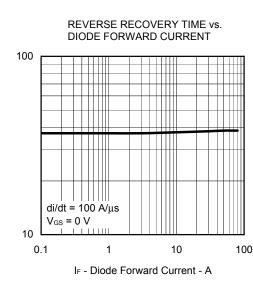


SWITCHING CHARACTERISTICS 1000 td(on), tr, td(off), tr - Switching Time - ns 100 10 VDD = 28 V tr Vgs = 10 V $R_G = 0 \Omega$ 1 0.1 10 100 1 ID - Drain Current - A

SOURCE TO DRAIN DIODE FORWARD VOLTAGE

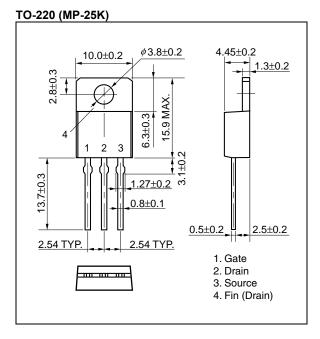


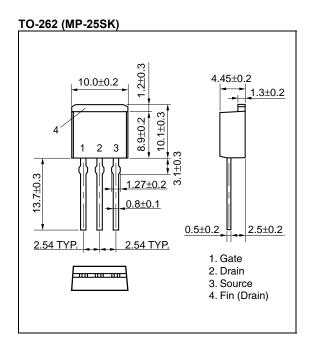
tr - Reverse Recovery Time - ns



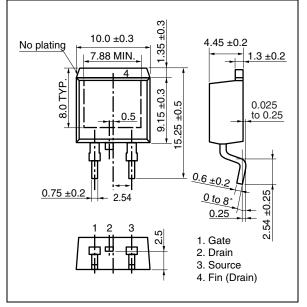
IF - Diode Forward Current - A

PACKAGE DRAWINGS (Unit: mm)

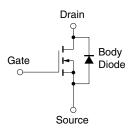




TO-263 (MP-25ZP)



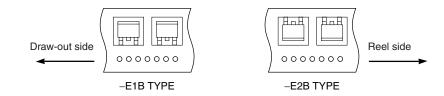
EQUIVALENT CIRCUIT



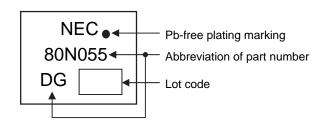
Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

TAPE INFORMATION (NP80N055PDG)

There are two types (-E1B, -E2B) of taping depending on the direction of the device.



MARKING INFORMATION



RECOMMENDED SOLDERING CONDITIONS

These products should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, please contact an NEC Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (http://www.necel.com/pkg/en/mount/index.html)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow NP80N055PDG	Maximum temperature (Package's surface temperature): 260°C or below Time at maximum temperature: 10 seconds or less Time of temperature higher than 220°C: 60 seconds or less Preheating time at 160 to 180°C: 60 to 120 seconds Maximum number of reflow processes: 3 times Maximum chlorine content of rosin flux (percentage mass): 0.2% or less	IR60-00-3
Wave soldering NP80N055MDG, NP80N055NDG	Maximum temperature (Solder temperature): 260°C or below Time: 10 seconds or less Maximum chlorine content of rosin flux: 0.2% (wt.) or less	THDWS
Partial heating NP80N055MDG, NP80N055NDG, NP80N055PDG	Maximum temperature (Pin temperature): 350°C or below Time (per side of the device): 3 seconds or less Maximum chlorine content of rosin flux: 0.2% (wt.) or less	P350

Caution Do not use different soldering methods together (except for partial heating).

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